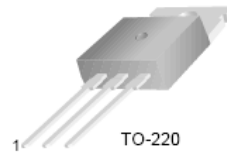


# TIP31/TIP31A/TIP31B/TIP31C

## NPN Epitaxial Silicon Transistor

### Features

- Complementary to TIP32/TIP32A/TIP32B/TIP32C



TO-220  
1. Base 2. Collector 3. Emitter

### Absolute Maximum Ratings $T_C=25^\circ\text{C}$ unless otherwise noted

| Symbol    | Parameter  | Value      | Units            |
|-----------|--|------------|------------------|
| $V_{CBO}$ | Collector-Base Voltage : TIP31                   | 40         | V                |
|           | : TIP31A   | 60         | V                |
|           | : TIP31B   | 80         | V                |
|           | : TIP31C   | 100        | V                |
| $V_{CEO}$ | Collector-Emitter Voltage : TIP31                | 40         | V                |
|           | : TIP31A   | 60         | V                |
|           | : TIP31B   | 80         | V                |
|           | : TIP31C   | 100        | V                |
| $V_{EBO}$ | Emitter-Base Voltage                             | 5          | V                |
| $I_C$     | Collector Current (DC)                           | 3          | A                |
| $I_{CP}$  | Collector Current (Pulse)                        | 5          | A                |
| $I_B$     | Base Current                                     | 1          | A                |
| $P_C$     | Collector Dissipation ( $T_C=25^\circ\text{C}$ ) | 40         | W                |
|           | Collector Dissipation ( $T_a=25^\circ\text{C}$ ) | 2          | W                |
| $T_J$     | Junction Temperature                             | 150        | $^\circ\text{C}$ |
| $T_{STG}$ | Storage Temperature                              | - 65 ~ 150 | $^\circ\text{C}$ |

**Electrical Characteristics**  $T_C=25^\circ\text{C}$  unless otherwise noted

| Symbol         | Parameter   | Test Condition  | Min.                  | Max.                     | Units  |
|----------------|---|---|-----------------------|--------------------------|--|
| $V_{CEO(sus)}$ | * Collector-Emitter Sustaining Voltage<br>: TIP31<br>: TIP31A<br>: TIP31B<br>: TIP31C | $I_C = 30\text{mA}, I_B = 0$  | 40<br>60<br>80<br>100 |                          | V<br>V<br>V<br>V   |
| $I_{CEO}$      | Collector Cut-off Current<br>: TIP31/31A<br>: TIP31B/31C                              | $V_{CE} = 30\text{V}, I_B = 0$<br>$V_{CE} = 60\text{V}, I_B = 0$  |                       | 0.3<br>0.3               | mA<br>mA   |
| $I_{CES}$      | Collector Cut-off Current<br>: TIP31<br>: TIP31A<br>: TIP31B<br>: TIP31C              | $V_{CE} = 40\text{V}, V_{EB} = 0$<br>$V_{CE} = 60\text{V}, V_{EB} = 0$<br>$V_{CE} = 80\text{V}, V_{EB} = 0$<br>$V_{CE} = 100\text{V}, V_{EB} = 0$ |                       | 200<br>200<br>200<br>200 | $\mu\text{A}$<br>$\mu\text{A}$<br>$\mu\text{A}$<br>$\mu\text{A}$ |
| $I_{EBO}$      | Emitter Cut-off Current   | $V_{EB} = 5\text{V}, I_C = 0$   |                       | 1                        | mA   |
| $h_{FE}$       | * DC Current Gain   | $V_{CE} = 4\text{V}, I_C = 1\text{A}$<br>$V_{CE} = 4\text{V}, I_C = 3\text{A}$  | 25<br>10              | 50                       |  |
| $V_{CE(sat)}$  | * Collector-Emitter Saturation Voltage  | $I_C = 3\text{A}, I_B = 375\text{mA}$   |                       | 1.2                      | V  |
| $V_{BE(sat)}$  | * Base-Emitter Saturation Voltage   | $V_{CE} = 4\text{V}, I_C = 3\text{A}$   |                       | 1.8                      | V  |
| $f_T$          | Current Gain Bandwidth Product  | $V_{CE} = 10\text{V}, I_C = 500\text{mA}, f = 1\text{MHz}$  | 3.0                   |                          | MHz  |

\* Pulse Test:  $PW \leq 300\text{ms}$ , Duty Cycle  $\leq 2\%$

# Typical Characteristics

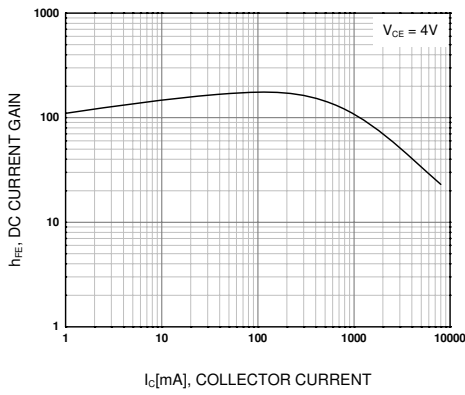


Figure 1. DC current Gain

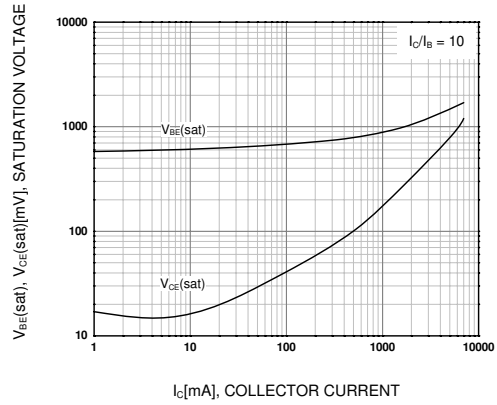


Figure 2. Base-Emitter Saturation Voltage  
Collector-Emitter Saturation Voltage

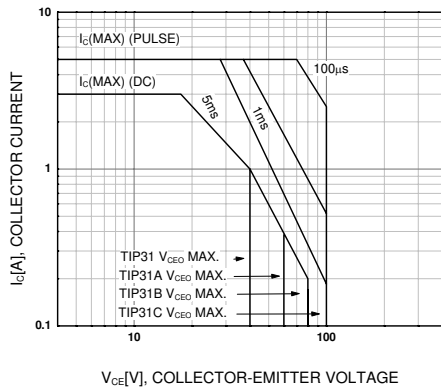


Figure 3. Safe Operating Area

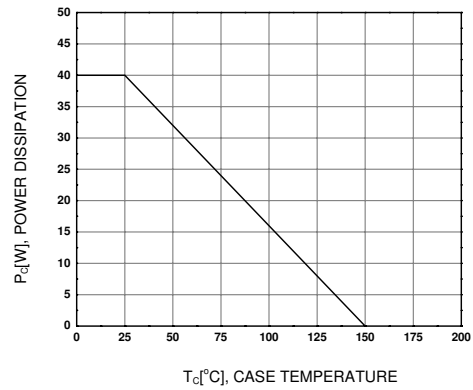


Figure 4. Power Derating





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